Vishay High Power Products

### HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 8 A



- Ultrafast recovery
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- Specified at operating conditions
- Designed and qualified for industrial level

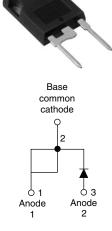
#### BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

#### DESCRIPTION

HFA08PB60 is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 8 A continuous current, the HFA08PB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>BBM</sub>) and does not exhibit any tendency to "snap-off" during the th portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08PB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V <sub>R</sub>		600	V
Maximum continuous forward current	١ <sub>F</sub>	T <sub>C</sub> = 100 °C	8	
Single pulse forward current	I <sub>FSM</sub>		60	А
Maximum repetitive forward current	I <sub>FRM</sub>		24	
Movimum power dissignation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	36	10/
Maximum power dissipation		T <sub>C</sub> = 100 °C	14	W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C



#### TO-247AC modified

PRODUCT SUMMARY				
V <sub>R</sub>	600 V			
V <sub>F</sub> at 8 A at 25 °C	1.7 V			
I <sub>F(AV)</sub>	8 A			
t <sub>rr</sub> (typical)	18 ns			
T <sub>J</sub> (maximum)	150 °C			
Q <sub>rr</sub> (typical)	65 nC			
dI <sub>(rec)M</sub> /dt (typical) at 125 °C	210 A/µs			
I <sub>RRM</sub> (typical)	3.5 A			



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<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		600	-	-	
	ge $V_{FM} = \frac{I_F = 8.0 \text{ A}}{I_F = 16 \text{ A}}$ See fig. IF = 8.0 A, TJ = 125 °C		-	1.4	1.7	v	
Maximum forward voltage		I <sub>F</sub> = 16 A	See fig. 1	-	1.7	2.1	
		I <sub>F</sub> = 8.0 A, T <sub>J</sub> = 125 °C		-	1.4	1.7	
Maximum reverse	1	$V_{R} = V_{R}$ rated	Coofin 0	-	0.3	5.0	
leakage current	I <sub>RM</sub>	$T_J$ = 125 °C, $V_R$ = 0.8 x $V_R$ rated	See fig. 2	-	100	500	μA
Junction capacitance	CT	V <sub>R</sub> = 200 V	See fig. 3	-	10	25	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8.0		-	nH		

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	18	-	
Reverse recovery time See fig. 5, 10	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8.0 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	37	55	ns
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	55	90	
Peak recovery current See fig. 6	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	3.5	5.0	A
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	4.5	8.0	
Reverse recovery charge	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	65	138	nC
See fig. 7	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	124	360	
Peak rate of fall of recovery current during t <sub>b</sub> See fig. 8	dl <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	240	-	A/µs
	dI <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	210	-	

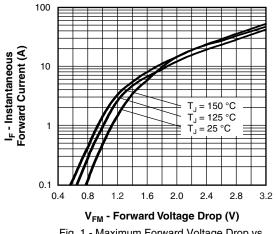
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	3.5	
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	K/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.25	-	
Waight			-	6.0	-	g
Weight			-	0.21	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)
Marking device		Case style TO-247AC modified (JEDEC)	HFA08PB60		-	



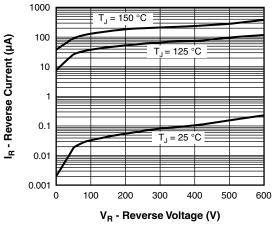
HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 8 A

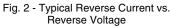
Vishay High Power Products

fast Soft Recovery Diode, 8 A









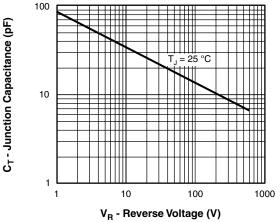
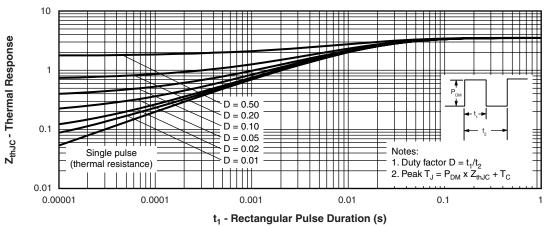


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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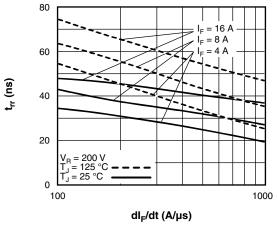


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt (Per Leg)

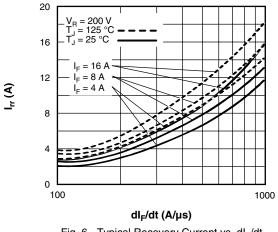
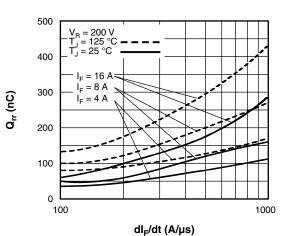
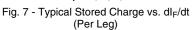


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt (Per Leg)





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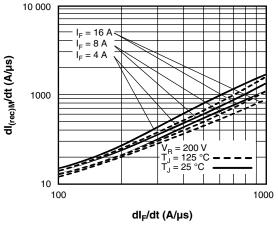


Fig. 8 - Typical dl<sub>(rec)M</sub>/dt vs. dl<sub>F</sub>/dt (Per Leg)



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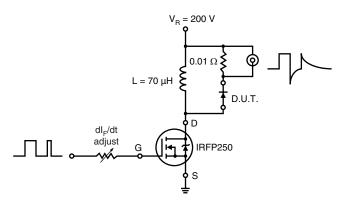


Fig. 9 - Reverse Recovery Parameter Test Circuit

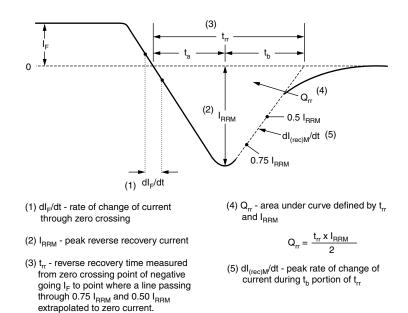


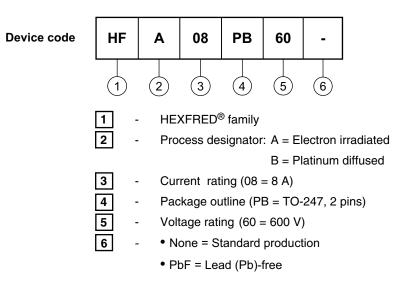
Fig. 10 - Reverse Recovery Waveform and Definitions

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#### ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95253				
Part marking information	http://www.vishay.com/doc?95255			



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